



Eldad Bahat-Treidel (Autor)
**GaN-Based HEMTs for High Voltage Operation: Design,
Technology and Characterization**



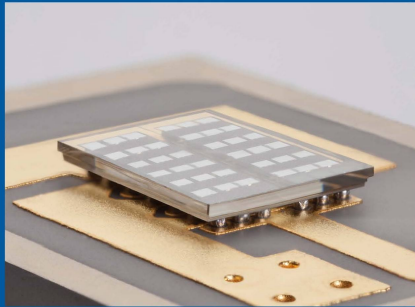
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GaN-Based HEMTs for High Voltage
Operation: Design, Technology and
Characterization



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